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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, EBI/EMI, I ² C, MMC/SD, QSPI, SCI, SSIE, SPI, UART/USART, USB
Peripherals	DMA, LCD, LVD, POR, PWM, WDT
Number of I/O	126
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	192K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 28x14b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	145-TFLGA
Supplier Device Package	145-TFLGA (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r7fs3a17c2a01clk-ac0

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1.5 Pin Functions

Function	Signal	I/O	Description
Power supply	VCC	Input	Power supply pin. Connect it to the system power supply. Connect this pin to VSS by a 0.1- μ F capacitor. The capacitor should be placed close to the pin.
	VCL	Input	Connect this pin to the VSS pin by the smoothing capacitor used to stabilize the internal power supply. Place the capacitor close to the pin.
	VSS	Input	Ground pin. Connect to the system power supply (0 V).
	VBATT	Input	Backup power pin
Clock	XTAL	Output	Pins for a crystal resonator. An external clock signal can be input through the EXTAL pin.
	EXTAL	Input	
	XCIN	Input	Input/output pins for the sub-clock oscillator. Connect a crystal resonator between XCOUT and XCIN.
	XCOUT	Output	
	EBCLK	Output	Outputs the external bus clock for external devices
	CLKOUT	Output	Clock output pin
Operating mode control	MD	Input	Pins for setting the operating mode. The signal levels on these pins must not be changed during operation mode transition on release from the reset state.
System control	RES	Input	Reset signal input pin. The MCU enters the reset state when this signal goes low.
CAC	CACREF	Input	Measurement reference clock input pin
Interrupt	NMI	Input	Non-maskable interrupt request pin
	IRQ0 to IRQ15	Input	Maskable interrupt request pins
KINT	KR00 to KR07	Input	A key interrupt can be generated by inputting a falling edge to the key interrupt input pins
On-chip debug	TMS	I/O	On-chip emulator or boundary scan pins
	TDI	Input	
	TCK	Input	
	TDO	Output	
	SWDIO	I/O	Serial wire debug data input/output pin
	SWCLK	Input	Serial wire clock pin
	SWO	Output	Serial wire trace output pin
External bus interface	RD	Output	Strobe signal indicating that reading from the external bus interface space is in progress, active-low
	WR	Output	Strobe signal indicating that writing to the external bus interface space is in progress, in 1-write strobe mode, active-low
	WR0, WR1	Output	Strobe signals indicating that either group of data bus pins (D07 to D00, D15 to D08) is valid in writing to the external bus interface space, in byte strobe mode, active-low
	BC0, BC1	Output	Strobe signals indicating that either group of data bus pins (D07 to D00, D15 to D08) is valid in access to the external bus interface space, in 1-write strobe mode, active-low
	ALE	Output	Address latch signal when address/data multiplexed bus is selected
	WAIT	Input	Input pin for wait request signals in access to the external space, active-low
	CS0 to CS3	Output	Select signals for CS areas, active-low
	A00 to A23	Output	Address bus
	D00 to D15	I/O	Data bus
Battery backup	VBATWIO0 to VBATWIO2	I/O	Output wakeup signal for the VBATT wakeup control function. External event input for the VBATT wakeup control function.

Function	Signal	I/O	Description
GPT	GTETRGA, GTETRGB	Input	External trigger input pin
	GTIOC0A to GTIOC9A, GTIOC0B to GTIOC9B	I/O	Input capture, Output capture, or PWM output pin
	GTIU	Input	Hall sensor input pin U
	GTIV	Input	Hall sensor input pin V
	GTIW	Input	Hall sensor input pin W
	GTOUUP	Output	3-phase PWM output for BLDC motor control (positive U phase)
	GTOULO	Output	3-phase PWM output for BLDC motor control (negative U phase)
	GTOVUP	Output	3-phase PWM output for BLDC motor control (positive V phase)
	GTOVLO	Output	3-phase PWM output for BLDC motor control (negative V phase)
	GTOWUP	Output	3-phase PWM output for BLDC motor control (positive W phase)
	GTOWLO	Output	3-phase PWM output for BLDC motor control (negative W phase)
AGT	AGTEE0, AGTEE1	Input	External event input enable
	AGTIO0, AGTIO1	I/O	External event input and pulse output
	AGTO0, AGTO1	Output	Pulse output
	AGTOA0, AGTOA1	Output	Output compare match A output
	AGTOB0, AGTOB1	Output	Output compare match B output
RTC	RTCOUT	Output	Output pin for 1-Hz/64-Hz clock
	RTCIC0 to RTCIC2	Input	Time capture event input pins
SCI	SCK0 to SCK4, SCK9	I/O	Input/output pins for the clock (clock synchronous mode)
	RXD0 to RXD4, RXD9	Input	Input pins for received data (asynchronous mode/clock synchronous mode)
	TXD0 to TXD4, TXD9	Output	Output pins for transmitted data (asynchronous mode/clock synchronous mode)
	CTS0_RTS0 to CTS4_RTS4, CTS9_RTS9	I/O	Input/output pins for controlling the start of transmission and reception (asynchronous mode/clock synchronous mode), active-low
	SCL0 to SCL4, SCL9	I/O	Input/output pins for the I ² C clock (simple IIC)
	SDA0 to SDA4, SDA9	I/O	Input/output pins for the I ² C data (simple IIC)
	SCK0 to SCK4, SCK9	I/O	Input/output pins for the clock (simple SPI)
	MISO0 to MISO4, MISO9	I/O	Input/output pins for slave transmission of data (simple SPI)
	MOSI0 to MOSI4, MOSI9	I/O	Input/output pins for master transmission of data (simple SPI)
IIC	SS0 to SS4, SS9	Input	Slave-select input pins (simple SPI), active-low
	SCL0 to SCL2	I/O	Input/output pins for clock
SSIE	SDA0 to SDA2	I/O	Input/output pins for data
	SSIBCK0	I/O	SSIE serial bit clock pin
	SSILRCK0/SSIFS0	I/O	Word select pins
	SSITXD0	Output	Serial data output pins
	SSIRXD0	Input	Serial data input pins
SPI	AUDIO_CLK	Input	External clock pin for audio (input oversampling clock)
	RSPCKA, RSPCKB	I/O	Clock input/output pin
	MOSIA, MOSIB	I/O	Input/output pins for data output from the master
	MISOA, MISOB	I/O	Input/output pins for data output from the slave
	SSLA0, SSLB0	I/O	Input/output pins for slave selection
	SSLA1, SSLA2, SSLA3, SSLB1, SSLB2, SSLB3	Output	Output pins for slave selection

Function	Signal	I/O	Description
QSPI	QSPCLK	Output	QSPI clock output pin
	QSSL	Output	QSPI slave output pin
	QIO0	I/O	Master transmit data/data 0
	QIO1	I/O	Master input data/data 1
	QIO2, QIO3	I/O	Data 2, Data 3
CAN	CRX0	Input	Receive data
	CTX0	Output	Transmit data
USBFS	VSS_USB	Input	Ground pins
	VCC_USB_LDO	Input	Power supply pin for USB LDO regulator
	VCC_USB	I/O	Input: Power supply pin for USB transceiver. Output: USB LDO regulator output pin. This pin should be connected to an external capacitor.
	USB_DP	I/O	D+ I/O pin of the USB on-chip transceiver. This pin should be connected to the D+ pin of the USB bus.
	USB_DM	I/O	D- I/O pin of the USB on-chip transceiver. This pin should be connected to the D- pin of the USB bus.
	USB_VBUS	Input	USB cable connection monitor pin. This pin should be connected to VBUS on the USB bus. The VBUS pin status (connected or disconnected) can be detected when the USB module is operating as a device controller.
	USB_EXICEN	Output	Low power control signal for external power supply (OTG) chip
	USB_VBUSEN	Output	VBUS (5 V) supply enable signal for external power supply chip
	USB_OVRCURA, USB_OVRCURB	Input	Connect the external overcurrent detection signals to these pins. Connect the VBUS comparator signals to these pins when the OTG power supply chip is connected.
USB_ID	Input	Connect the MicroAB connector ID input signal to this pin during operation in OTG mode	
SDHI	SD0CLK	Output	SD clock output pin
	SD0CMD	I/O	SD command output, response input signal pin
	SD0DAT0 to SD0DAT7	I/O	SD data bus pins
	SD0CD	Input	SD card detection pin
	SD0WP	Input	SD write-protect signal
Analog power supply	AVCC0	Input	Analog voltage supply pin
	AVSS0	Input	Analog voltage supply ground pin
	VREFH0	Input	Analog reference voltage supply pin
	VREFL0	Input	Reference power supply ground pin
	VREFH	Input	Analog reference voltage supply pin for D/A converter
VREFL	Input	Analog reference ground pin for D/A converter	
ADC14	AN000 to AN027	Input	Input pins for the analog signals to be processed by the A/D converter
	ADTRG0	Input	Input pins for the external trigger signals that start the A/D conversion, active-low
DAC12	DA0	Output	Output pins for the analog signals to be processed by the D/A converter
Comparator output	VCOUT	Output	Comparator output pin
ACMPLP	COMPREF0, COMPREF1	Input	Reference voltage input pins
	CMPIN0, CMPIN1	Input	Analog voltage input pins
OPAMP	AMP0+ to AMP3+	Input	Analog voltage input pins
	AMP0- to AMP3-	Input	Analog voltage input pins
	AMP00 to AMP30	Output	Analog voltage output pins
CTSU	TS00 to TS13, TS17 to TS22, TS27 to TS31, TS34, TS35	Input	Capacitive touch detection pins (touch pins)
	TSCAP	—	Secondary power supply pin for the touch driver

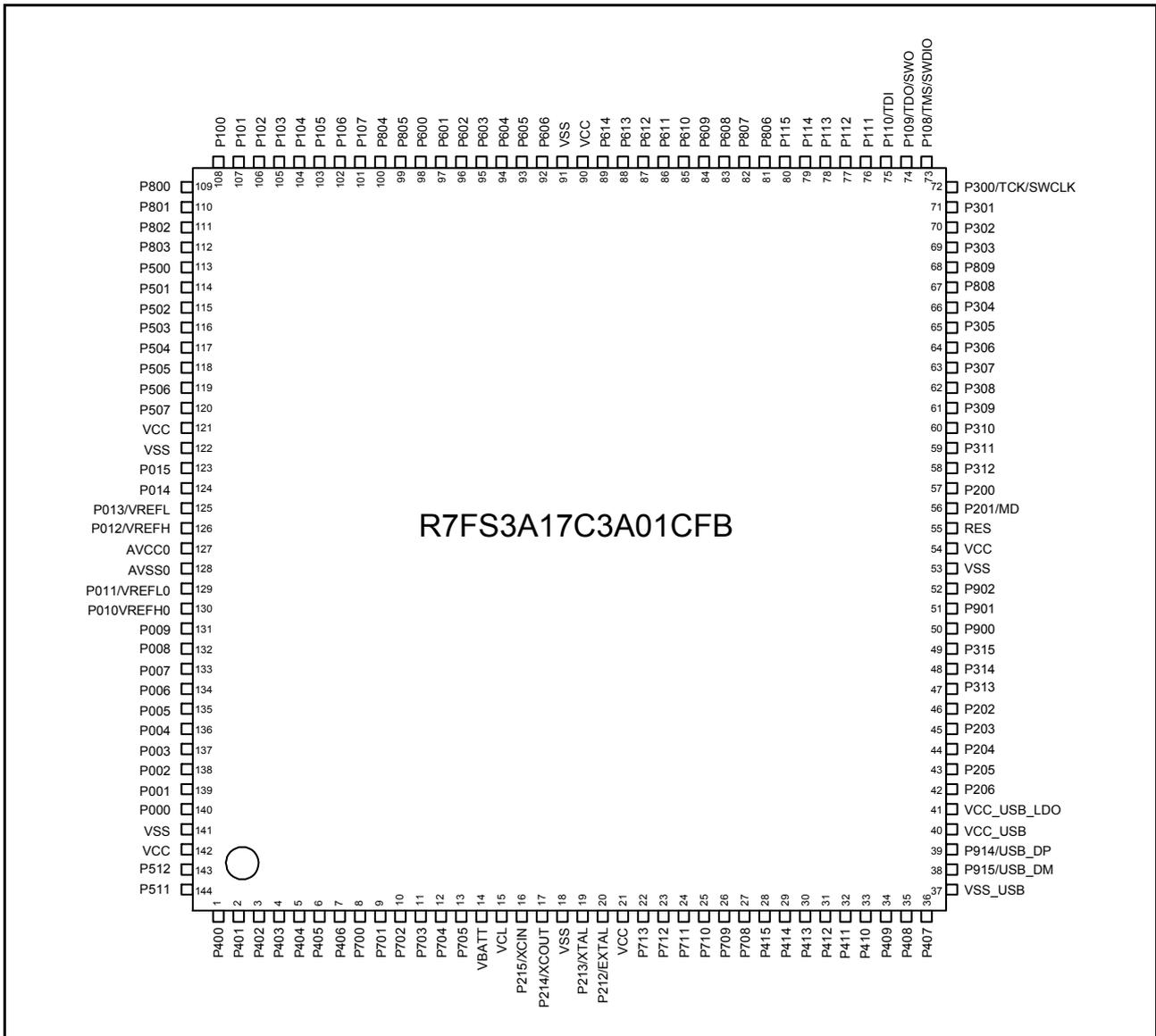


Figure 1.4 Pin assignment for 144-pin LQFP (top view)

2.2.3 I/O I_{OH} , I_{OL} **Table 2.6** I/O I_{OH} , I_{OL} (1 of 2)

Conditions: VCC = AVCC0 = VCC_USB = VCC_USB_LCO = 1.6 to 5.5 V

Parameter			Symbol	Min	Typ	Max	Unit
Permissible output current (average value per pin)	Ports P212, P213	-	I_{OH}	-	-	-4.0	mA
			I_{OL}	-	-	4.0	mA
	Port P408	Low drive*1	I_{OH}	-	-	-4.0	mA
			I_{OL}	-	-	4.0	mA
		Middle drive for IIC Fast-mode*4 VCC = 2.7 to 5.5 V	I_{OH}	-	-	-8.0	mA
			I_{OL}	-	-	8.0	mA
		Middle drive*2 VCC = 3.0 to 5.5 V	I_{OH}	-	-	-20.0	mA
			I_{OL}	-	-	20.0	mA
	Port P409	Low drive*1	I_{OH}	-	-	-4.0	mA
			I_{OL}	-	-	4.0	mA
		Middle drive*2 VCC = 2.7 to 3.0 V	I_{OH}	-	-	-8.0	mA
			I_{OL}	-	-	8.0	mA
		Middle drive*2 VCC = 3.0 to 5.5 V	I_{OH}	-	-	-20.0	mA
			I_{OL}	-	-	20.0	mA
	Ports P100 to P115, P201 to P204, P300 to P315, P500 to P503, P600 to P606, P608 to P614, P800 to P809, P900 to P902 (total 67 pins)	Low drive*1	I_{OH}	-	-	-4.0	mA
			I_{OL}	-	-	4.0	mA
		Middle drive*2	I_{OH}	-	-	-4.0	mA
			I_{OL}	-	-	8.0	mA
	Ports P914, P915	-	I_{OH}	-	-	-4.0	mA
			I_{OL}	-	-	4.0	mA
Other output pin*3	Low drive*1	I_{OH}	-	-	-4.0	mA	
		I_{OL}	-	-	4.0	mA	
	Middle drive*2	I_{OH}	-	-	-8.0	mA	
		I_{OL}	-	-	8.0	mA	

Table 2.14 Operating and standby current (4)

Conditions: VCC = AVCC0 = 1.6 to 5.5 V, VREFH0 = 2.7 V to AVCC0

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions	
Analog power supply current	During A/D conversion (at high-speed conversion)	I _{AVCC}	-	-	3.0	mA	-	
	During A/D conversion (at low power conversion)		-	-	1.0	mA	-	
	During D/A conversion (per channel)*1		-	0.4	0.8	mA	-	
	Waiting for A/D and D/A conversion (all units)*6		-	-	1.0	μA	-	
Reference power supply current	During A/D conversion	I _{REFH0}	-	-	150	μA	-	
	Waiting for A/D conversion (all units)		-	-	60	nA	-	
	During D/A conversion	I _{REFH}	-	50	100	μA	-	
	Waiting for D/A conversion (all units)		-	-	100	μA	-	
Temperature sensor		I _{TNS}	-	75	-	μA	-	
Low-Power Analog Comparator operating current	Window mode	I _{CMLP}	-	15	-	μA	-	
	Comparator High-speed mode		-	10	-	μA	-	
	Comparator Low-speed mode		-	2	-	μA	-	
	Comparator Low-speed mode using DAC8		-	820	-	μA	-	
Operational Amplifier operating current	Low power mode	I _{AMP}	1 unit operating	-	2.5	4.0	μA	-
			2 units operating	-	4.5	8.0	μA	-
			3 units operating	-	6.5	11.0	μA	-
			4 units operating	-	8.5	14.0	μA	-
	High speed mode		1 unit operating	-	140	220	μA	-
			2 units operating	-	280	410	μA	-
			3 units operating	-	420	600	μA	-
			4 units operating	-	560	780	μA	-
LCD operating current	External resistance division method f _{LCD} = f _{SUB} = 128 Hz, 1/3 bias, and 4-time slice	I _{LCD1} *5	-	0.34	-	μA	-	
	Internal voltage boosting method (VLCD.VLCD = 04) f _{LCD} = f _{SUB} = 128 Hz, 1/3 bias, and 4-time slice	I _{LCD2} *5	-	0.92	-	μA	-	
	Capacitor split method f _{LCD} = f _{SUB} = 128 Hz, 1/3 bias, and 4-time slice	I _{LCD3} *5	-	0.19	-	μA	-	
USB operating current	During USB communication operation under the following settings and conditions: • Host controller operation is set to full-speed mode Bulk OUT transfer (64 bytes) × 1, bulk IN transfer (64 bytes) × 1 • Connect peripheral devices via a 1-meter USB cable from the USB port.	I _{USBH} *2	-	4.3 (VCC) 0.9 (VCC_USB)*4	-	mA	-	
	During USB communication operation under the following settings and conditions: • Device controller operation is set to full-speed mode Bulk OUT transfer (64 bytes) × 1, bulk IN transfer (64 bytes) × 1 • Connect the host device via a 1-meter USB cable from the USB port.	I _{USBF} *2	-	3.6 (VCC) 1.1 (VCC_USB)*4	-	mA	-	
	During suspended state under the following setting and conditions: • Device controller operation is set to full-speed mode (pull up the USB_DP pin) • Software standby mode • Connect the host device via a 1-meter USB cable from the USB port.	I _{SUSP} *3	-	0.35 (VCC) 170 (VCC_USB)*4	-	μA	-	

Note 1. The reference power supply current is included in the power supply current value for D/A conversion.

Note 2. Current consumed only by the USBFS.

Note 3. Includes the current supplied from the pull-up resistor of the USB_DP pin to the pull-down resistor of the host device, in addition to the current consumed by the MCU during the suspended state.

Note 4. When VCC = VCC_USB = 3.3 V.

Note 5. Current flowing only to the LCD controller. Not including the current that flows through the LCD panel.

Note 6. When the MCU is in Software Standby mode or the MSTPCRD.MSTPD16 (ADC140 Module Stop bit) is in the module-stop state.

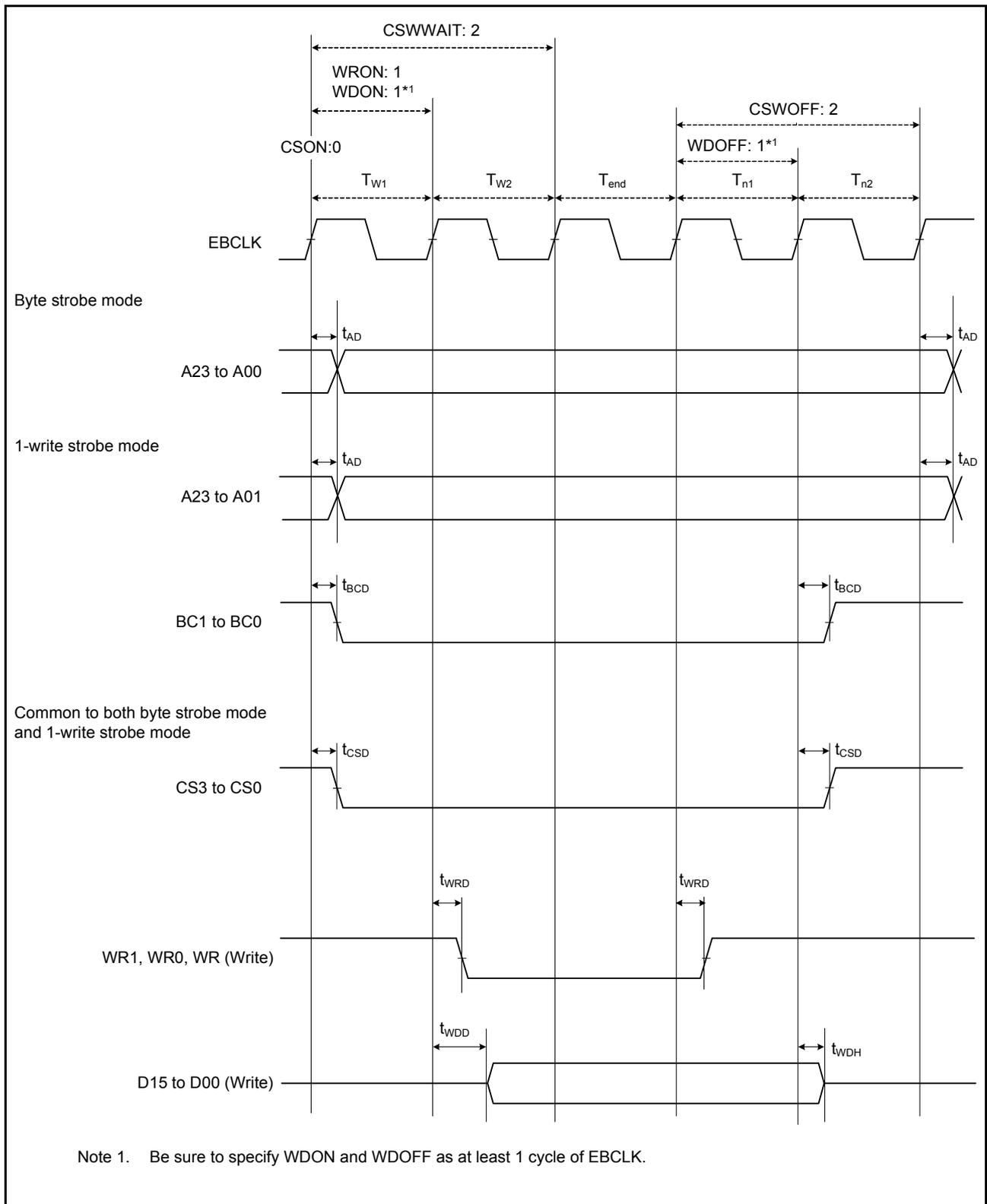


Figure 2.43 External bus timing/normal write cycle (bus clock synchronized)

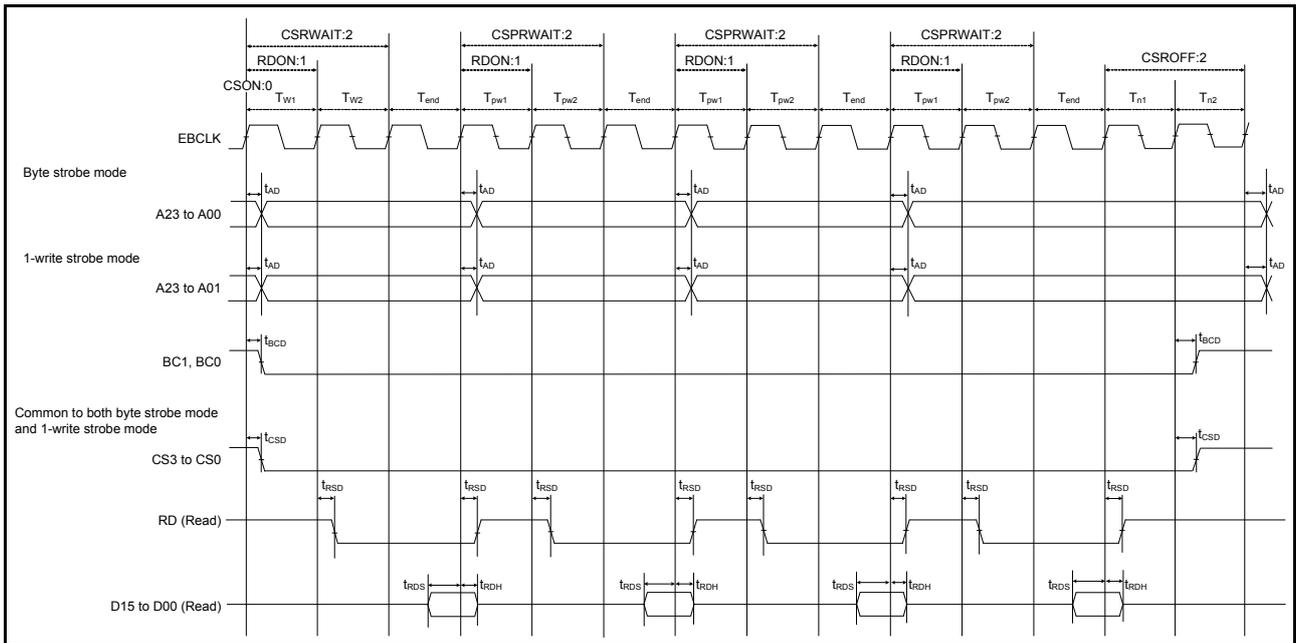
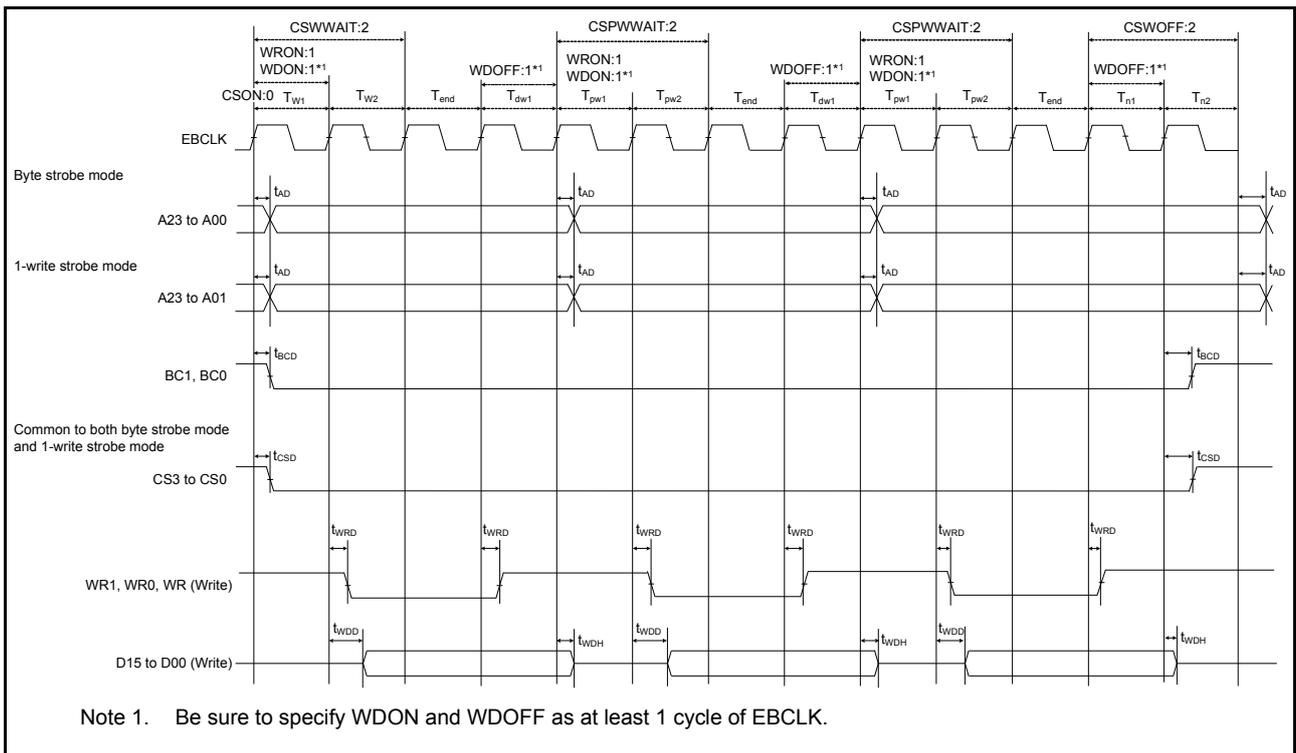


Figure 2.44 External bus timing/page read cycle (bus clock synchronized)



Note 1. Be sure to specify WDON and WDOFF as at least 1 cycle of EBCLK.

Figure 2.45 External bus timing/page write cycle (bus clock synchronized)

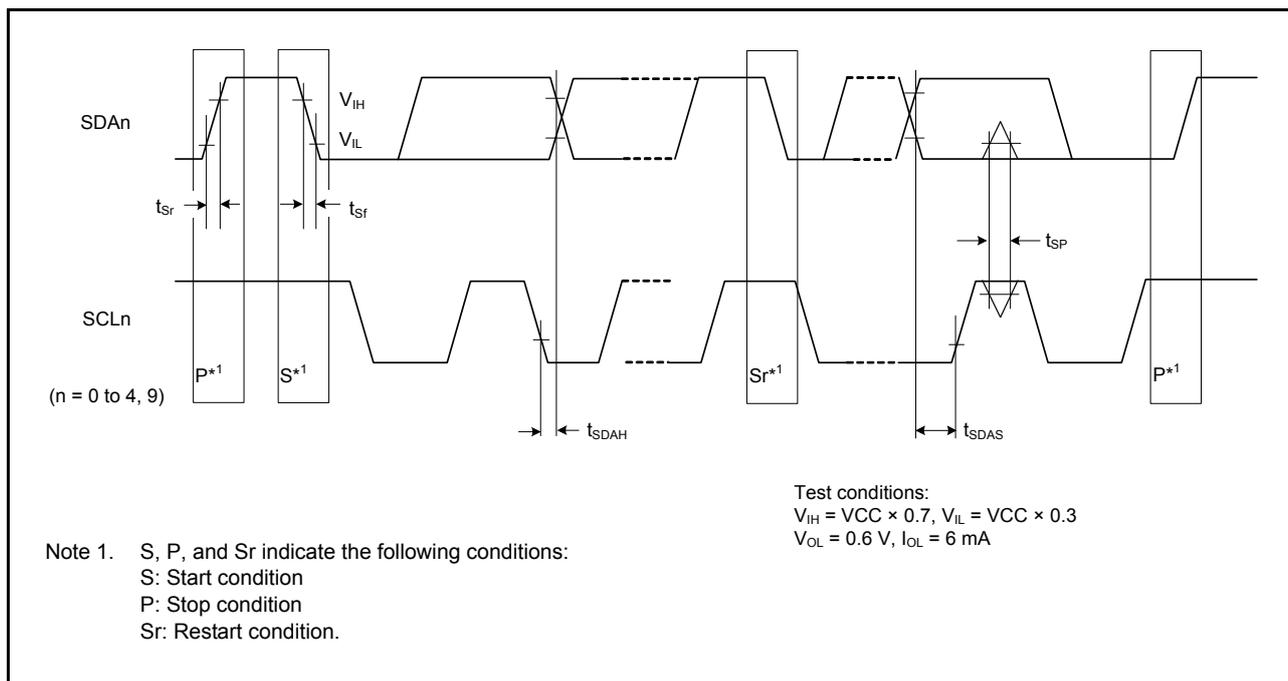


Figure 2.60 SCI simple IIC mode timing

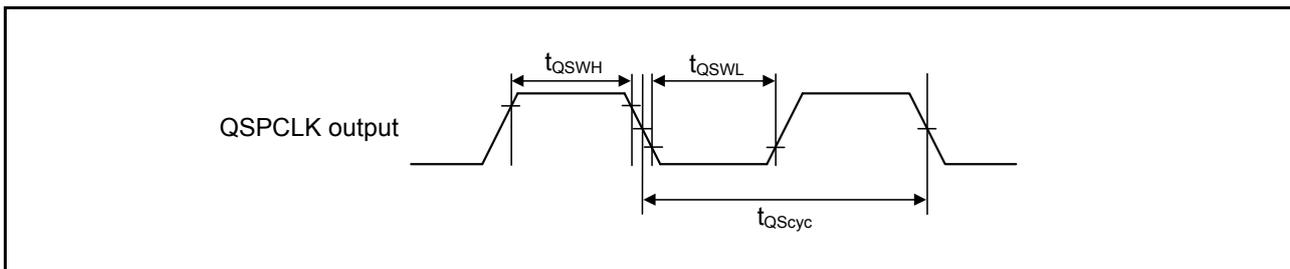


Figure 2.68 QSPI clock timing

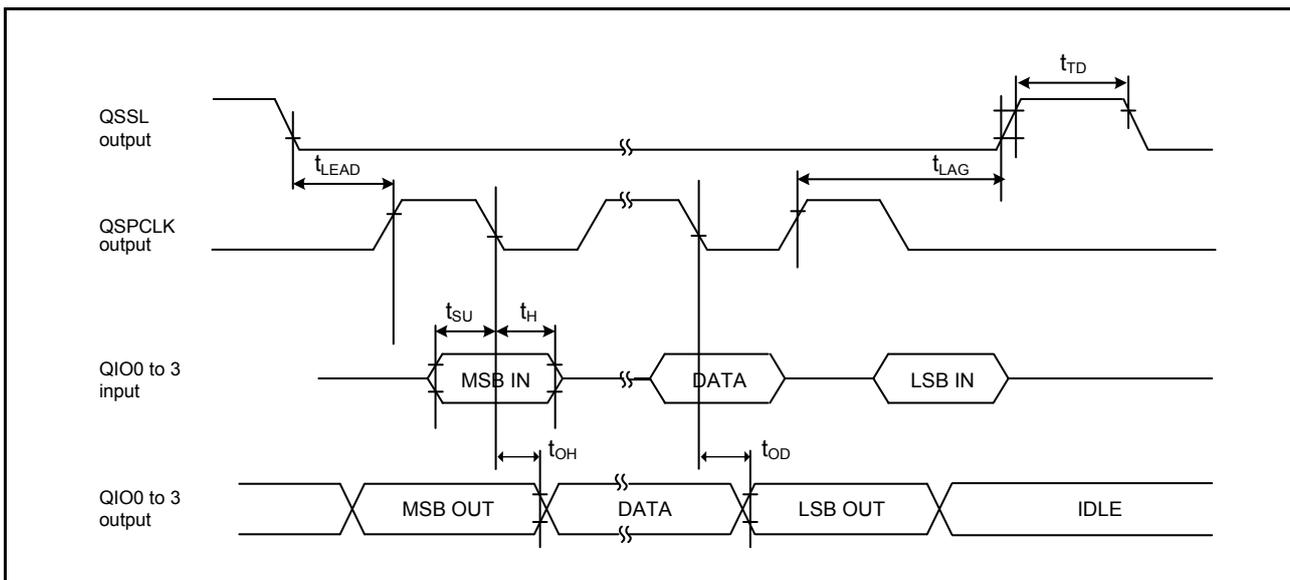


Figure 2.69 Transfer/receive timing

2.3.15 CLKOUT Timing

Table 2.45 CLKOUT timing

Parameter		Symbol	Min	Max	Unit*1	Test conditions	
CLKOUT	CLKOUT pin output cycle*1	VCC = 2.7 V or above	t _{Cyc}	62.5	-	ns	Figure 2.76
		VCC = 1.8 V or above		125	-		
		VCC = 1.6 V or above		250	-		
	CLKOUT pin high pulse width*2	VCC = 2.7 V or above	t _{CH}	15	-	ns	
		VCC = 1.8 V or above		30	-		
		VCC = 1.6 V or above		150	-		
	CLKOUT pin low pulse width*2	VCC = 2.7 V or above	t _{CL}	15	-	ns	
		VCC = 1.8 V or above		30	-		
		VCC = 1.6 V or above		150	-		
	CLKOUT pin output rise time	VCC = 2.7 V or above	t _{Cr}	-	12	ns	
		VCC = 1.8 V or above		-	25		
		VCC = 1.6 V or above		-	50		
CLKOUT pin output fall time	VCC = 2.7 V or above	t _{Cf}	-	12	ns		
	VCC = 1.8 V or above		-	25			
	VCC = 1.6 V or above		-	50			

Note 1. When the EXTAL external clock input or an oscillator is used with division by 1 (the CKOCR.CKOSSEL[2:0] bits are 011b and the CKOCR.CKODIV[2:0] bits are 000b) to output from CLKOUT, the above should be satisfied with an input duty cycle of 45 to 55%.

Note 2. When the MOCO is selected as the clock output source (the CKOCR.CKOSSEL[2:0] bits are 001b), set the clock output division ratio selection to be divided by 2 (the CKOCR.CKODIV[2:0] bits are 001b).

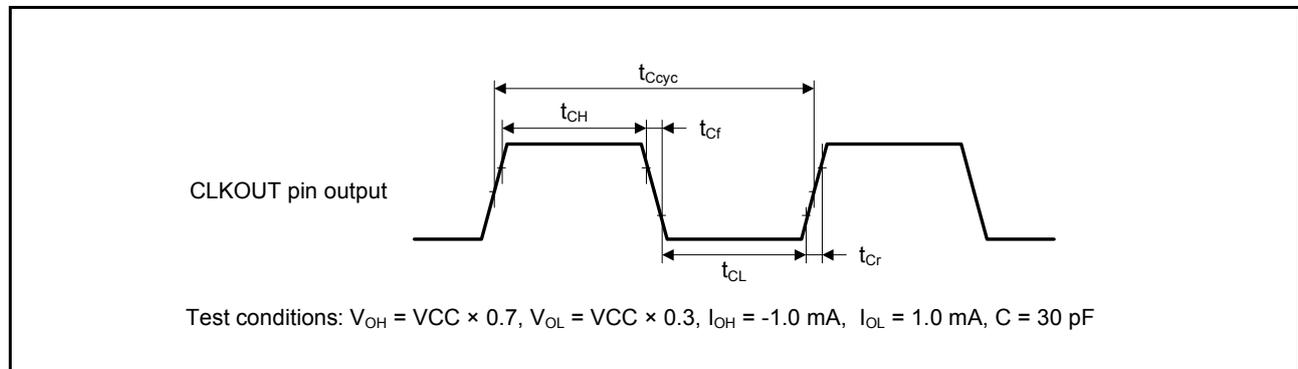


Figure 2.76 CLKOUT output timing

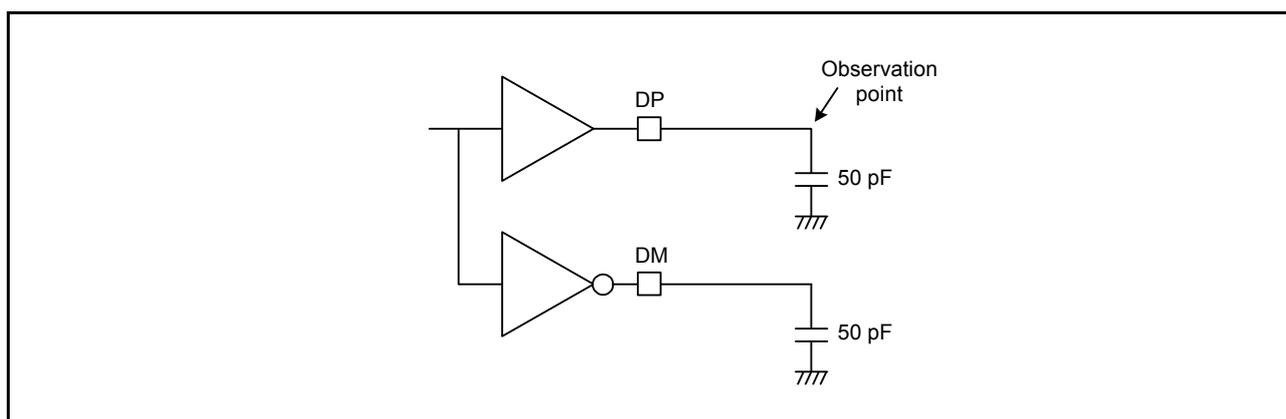


Figure 2.78 Test circuit for Full-Speed (FS) connection

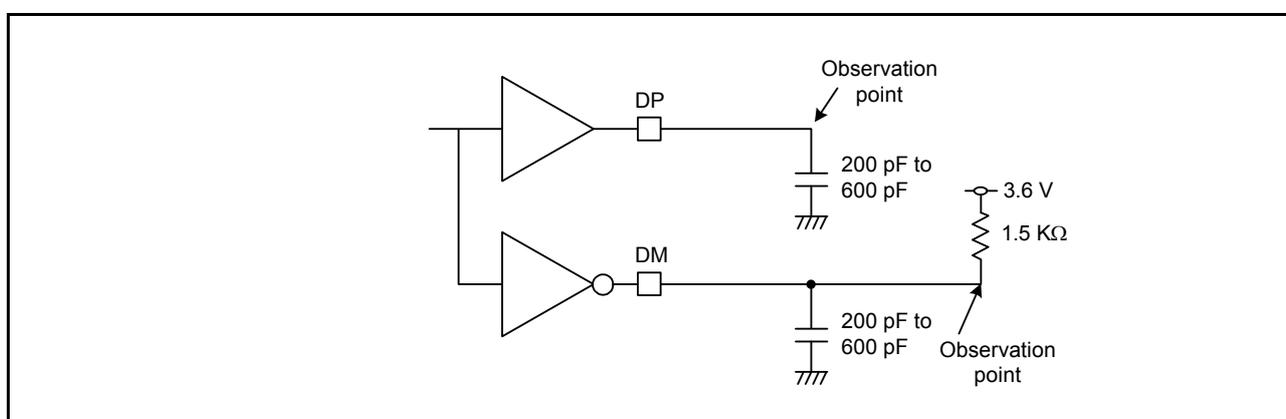


Figure 2.79 Test circuit for Low-Speed (LS) connection

2.4.2 USB External Supply

Table 2.47 USB regulator

Parameter	Min	Typ	Max	Unit	Test conditions	
VCC_USB supply current	VCC_USB_LDO ≥ 3.8V	-	-	50	mA	-
	VCC_USB_LDO ≥ 4.5V	-	-	100	mA	-
VCC_USB supply voltage	3.0	-	3.6	V	-	

2.5 ADC14 Characteristics

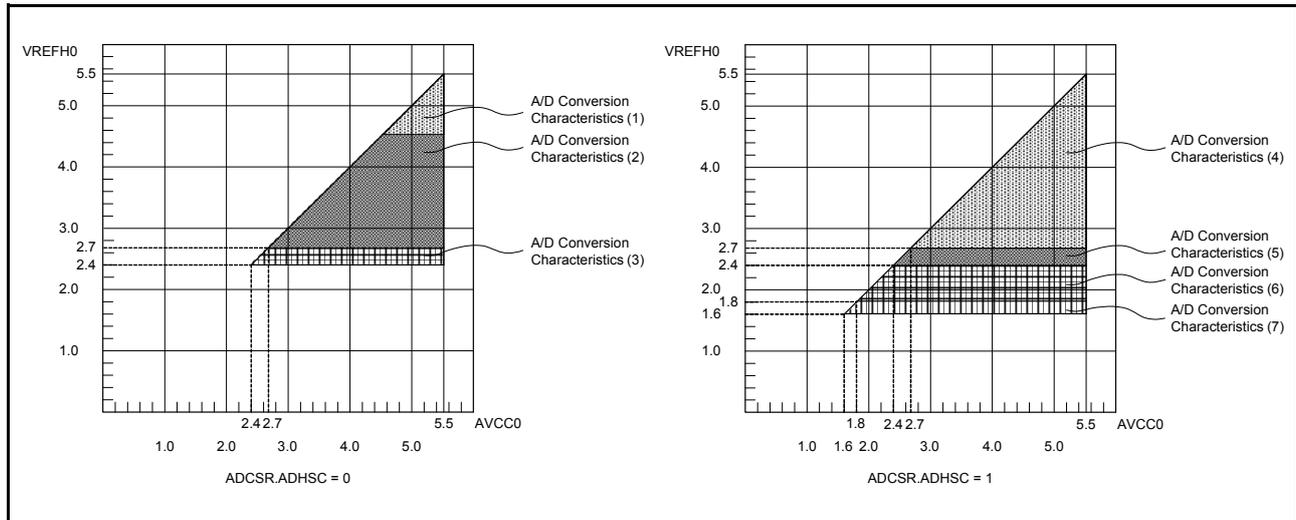


Figure 2.80 AVCC0 to VREFH0 voltage range

Table 2.48 A/D conversion characteristics (1) in high-speed A/D conversion mode (1 of 2)

Conditions: $V_{CC} = AV_{CC0} = 4.5$ to 5.5 V, $V_{REFH0} = 4.5$ to 5.5 V
Reference voltage range applied to the V_{REFH0} and V_{REFL0} .

Parameter	Min	Typ	Max	Unit	Test conditions	
Frequency	1	-	64	MHz	-	
Analog input capacitance*2	Cs	-	8 (reference data)	pF	High-precision channel	
		-	9 (reference data)	pF	Normal-precision channel	
Analog input resistance	Rs	-	2.5 (reference data)	k Ω	High-precision channel	
		-	6.7 (reference data)	k Ω	Normal-precision channel	
Analog input voltage range	Ain	0	VREFH0	V	-	
12-bit mode						
Resolution	-	-	12	Bit	-	
Conversion time*1 (Operation at PCLKC = 64 MHz)	Permissible signal source impedance Max. = 0.3 k Ω	0.70	-	-	μ s	High-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 0Dh
		1.13	-	-	μ s	Normal-precision channel ADCSR.ADHSC = 0 ADSSTRn.SST[7:0] = 28h
Offset error	-	± 0.5	± 4.5	LSB	High-precision channel	
			± 6.0	LSB	Other than above	
Full-scale error	-	± 0.75	± 4.5	LSB	High-precision channel	
			± 6.0	LSB	Other than above	
Quantization error	-	± 0.5	-	LSB	-	
Absolute accuracy	-	± 1.25	± 5.0	LSB	High-precision channel	
			± 8.0	LSB	Other than above	
DNL differential nonlinearity error	-	± 1.0	-	LSB	-	
INL integral nonlinearity error	-	± 1.0	± 3.0	LSB	-	
14-bit mode						
Resolution	-	-	14	Bit	-	

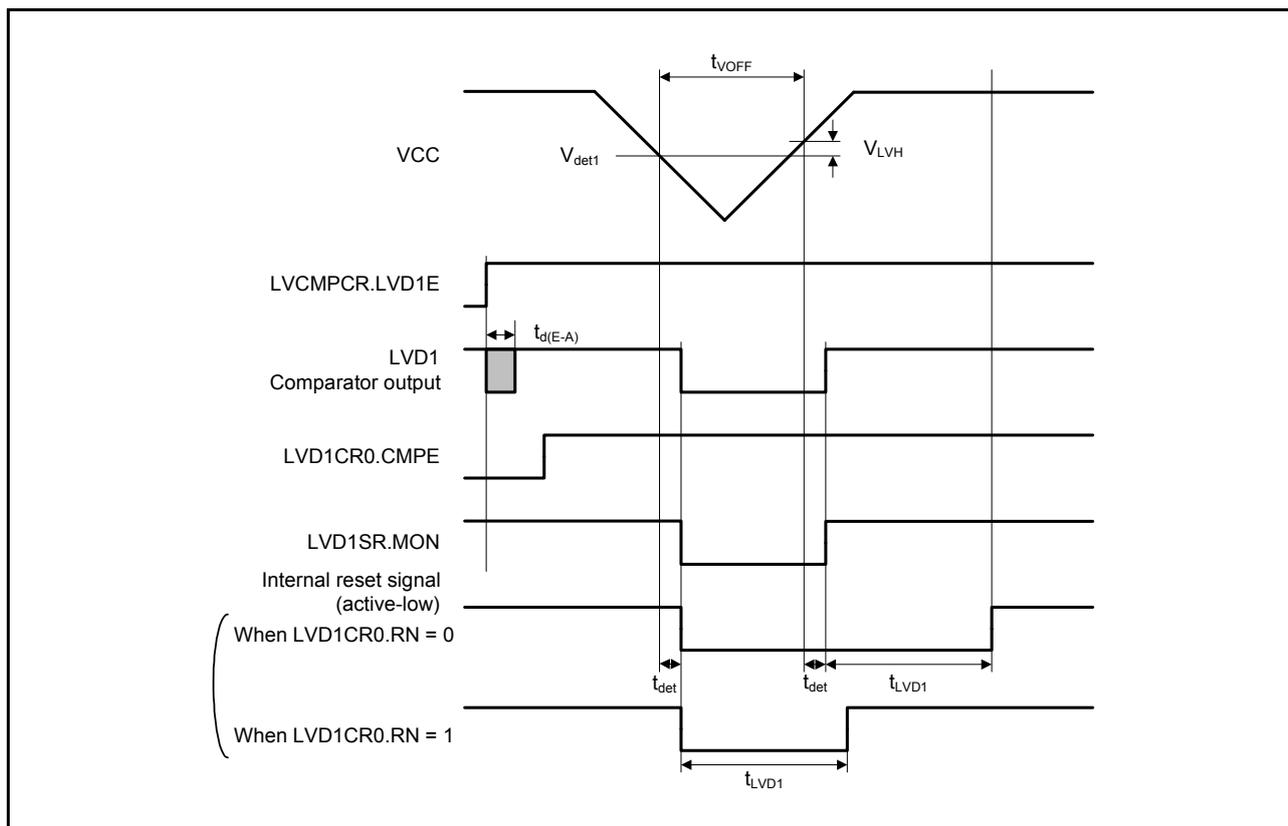


Figure 2.88 Voltage detection circuit timing (V_{det1})

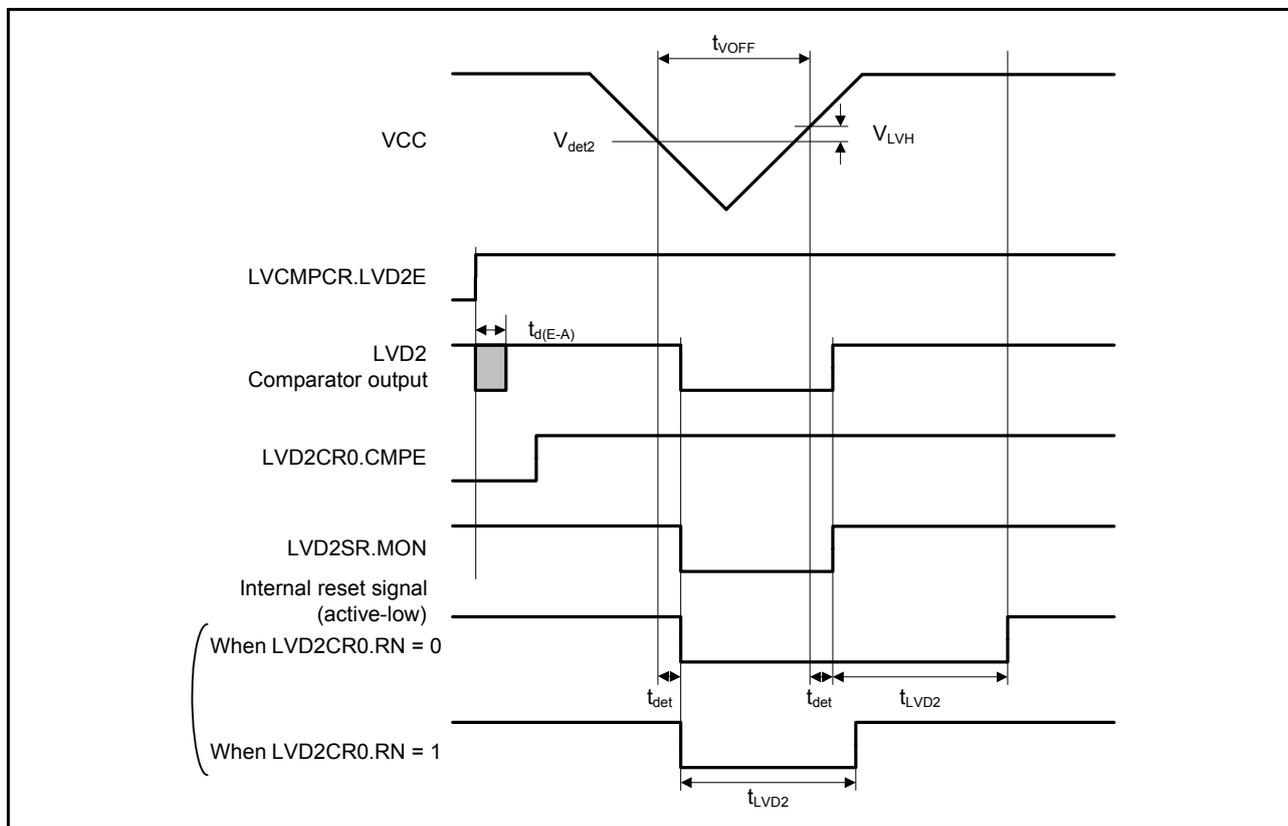


Figure 2.89 Voltage detection circuit timing (V_{det2})

[1/4 Bias Method]

Table 2.71 Internal voltage boosting method LCD characteristics

Conditions: VCC = 1.8 V to 5.5 V

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	Test conditions	
LCD output voltage variation range	V _{L1}	C1 to C5*1 = 0.47 μF	VLCD = 04h	0.90	1.0	1.08	V	-
			VLCD = 05h	0.95	1.05	1.13	V	-
			VLCD = 06h	1.00	1.10	1.18	V	-
			VLCD = 07h	1.05	1.15	1.23	V	-
			VLCD = 08h	1.10	1.20	1.28	V	-
			VLCD = 09h	1.15	1.25	1.33	V	-
			VLCD = 0Ah	1.20	1.30	1.38	V	-
			VLCD = 0Bh	1.25	1.35	1.43	V	-
			VLCD = 0Ch	1.30	1.40	1.48	V	-
Doubler output voltage	V _{L2}	C1 to C5*1 = 0.47 μF	2V _{L1} - 0.08	2V _{L1}	2V _{L1}	V	-	
Tripler output voltage	V _{L3}	C1 to C5*1 = 0.47 μF	3V _{L1} - 0.12	3V _{L1}	3V _{L1}	V	-	
Quadruply output voltage	V _{L4} *4	C1 to C5*1 = 0.47 μF	4V _{L1} - 0.16	4V _{L1}	4V _{L1}	V	-	
Reference voltage setup time*2	t _{VL1S}		5	-	-	ms	Figure 2.93	
LCD output voltage variation range*3	t _{VLWT}	C1 to C5*1 = 0.47 μF	500	-	-	ms		

Note 1. This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between VL1 and GND

C3: A capacitor connected between VL2 and GND

C4: A capacitor connected between VL3 and GND

C5: A capacitor connected between VL4 and GND

C1 = C2 = C3 = C4 = C5 = 0.47 μF ± 30%

Note 2. This is the time required to wait from when the reference voltage is specified by using the VLCD register or when the internal voltage boosting method is selected (by setting the MDSET[1] and MDSET[0] bits in the LCDM0 register to 01b) if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).

Note 3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

Note 4. V_{L4} must be 5.5 V or lower.

2.12.3 Capacitor Split Method

[1/3 Bias Method]

Table 2.72 Internal voltage boosting method LCD characteristics

Conditions: VCC = 2.2 V to 5.5 V

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	Test conditions
VL4 voltage*1	V _{L4}	C1 to C4 = 0.47 μF*2	-	VCC	-	V	-
VL2 voltage*1	V _{L2}	C1 to C4 = 0.47 μF*2	2/3 × V _{L4} - 0.07	2/3 × V _{L4}	2/3 × V _{L4} + 0.07	V	-
VL1 voltage*1	V _{L1}	C1 to C4 = 0.47 μF*2	1/3 × V _{L4} - 0.08	1/3 × V _{L4}	1/3 × V _{L4} + 0.08	V	-
Capacitor split wait time*1	t _{WAIT}		100	-	-	ms	Figure 2.93

Note 1. This is the wait time from when voltage bucking is started (VLCON = 1) until display is enabled (LCDON = 1).

Note 2. This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between VL1 and GND

C3: A capacitor connected between VL2 and GND

C4: A capacitor connected between VL4 and GND

C1 = C2 = C3 = C4 = 0.47 μF ± 30%.

Appendix 1. Package Dimensions

Information on the latest version of the package dimensions or mountings is displayed in “Packages” on the Renesas Electronics Corporation website.

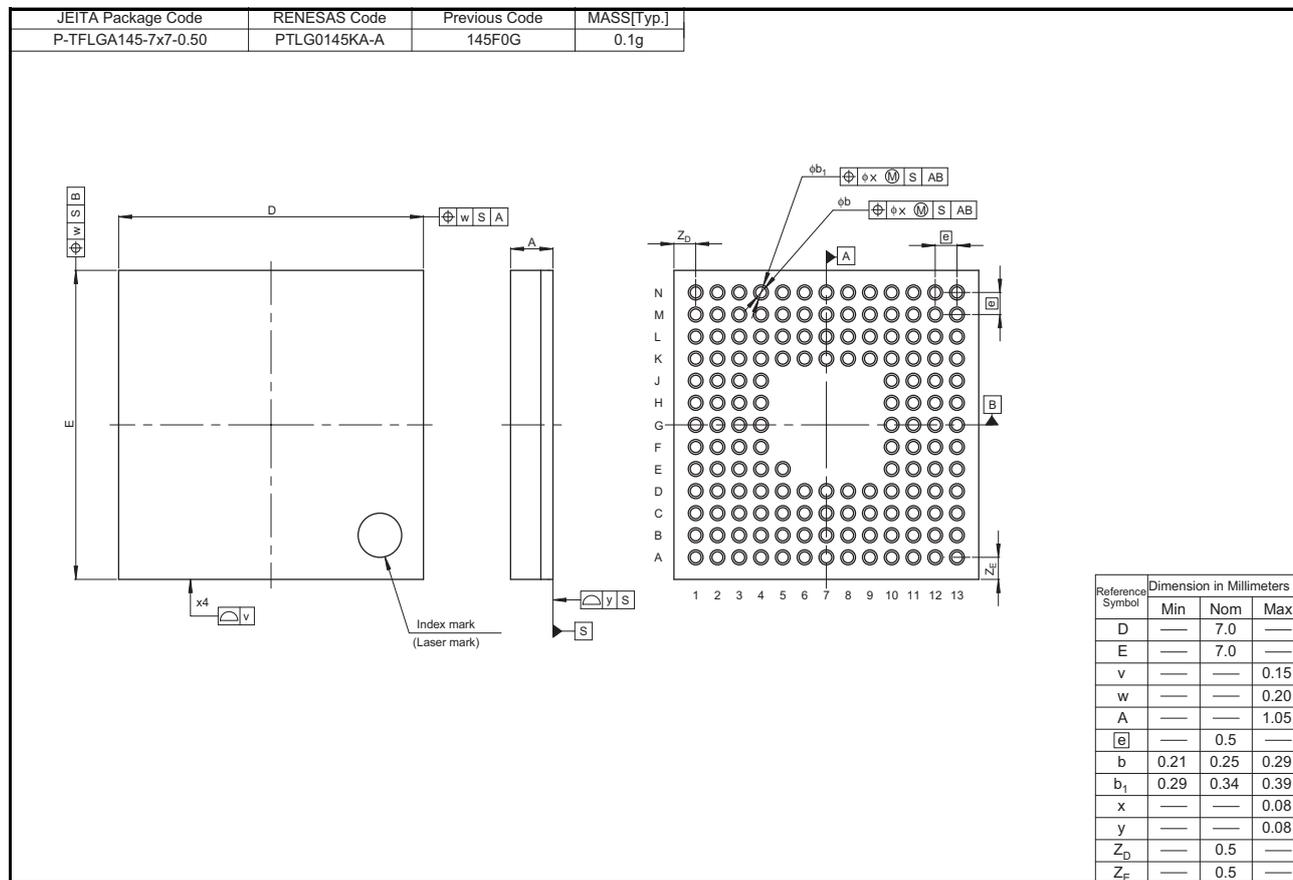
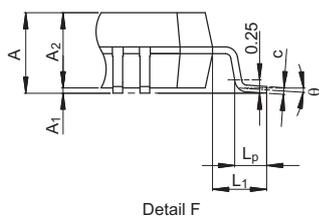
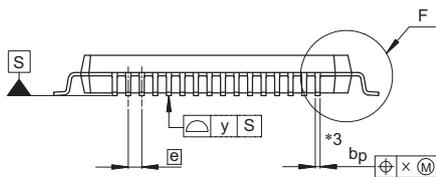
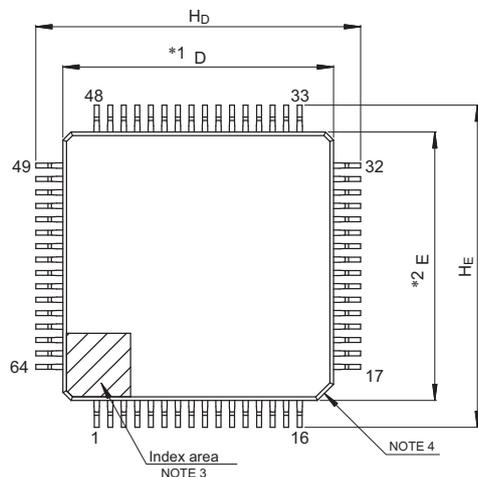


Figure 1.1 LGA 145-pin

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFQFP64-10x10-0.50	PLQP0064KB-C	—	0.3

Unit: mm



NOTE)

1. DIMENSIONS **1* AND **2* DO NOT INCLUDE MOLD FLASH.
2. DIMENSION **3* DOES NOT INCLUDE TRIM OFFSET.
3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.

Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	9.9	10.0	10.1
E	9.9	10.0	10.1
A ₂	—	1.4	—
H _D	11.8	12.0	12.2
H _E	11.8	12.0	12.2
A	—	—	1.7
A ₁	0.05	—	0.15
b _p	0.15	0.20	0.27
c	0.09	—	0.20
θ	0°	3.5°	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L _p	0.45	0.6	0.75
L ₁	—	1.0	—

Figure 1.6 LQFP 64-pin

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